

N-channel 60 V, 0.003  $\Omega$  typ., 130 A STripFET™ F7  
 Power MOSFET in a PowerFLAT™ 5x6 package

Datasheet - production data

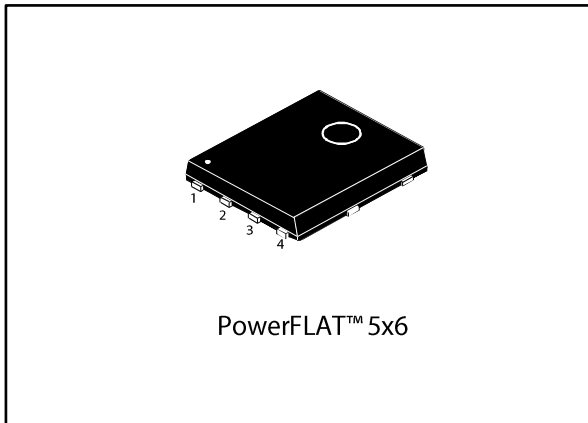
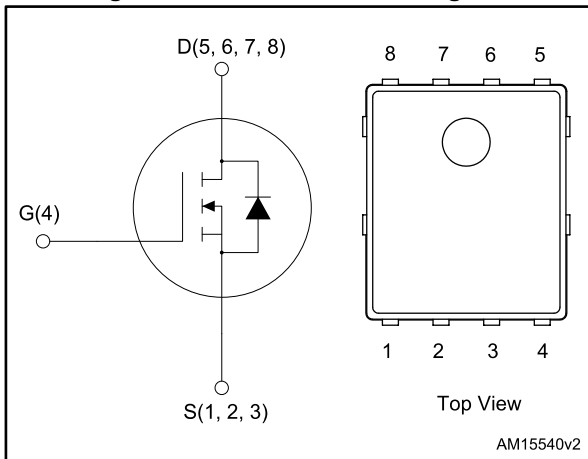


Figure 1: Internal schematic diagram



**Features**

Order code	V <sub>DS</sub>	R <sub>DS(on)</sub> max	I <sub>D</sub>
STL130N6F7	60 V	0.0035 $\Omega$	130 A

- Among the lowest R<sub>DS(on)</sub> on the market
- Excellent figure of merit (FoM)
- Low C<sub>rss</sub>/C<sub>iss</sub> ratio for EMI immunity
- High avalanche ruggedness

**Applications**

- Switching applications

**Description**

This N-channel Power MOSFET utilizes STripFET™ F7 technology with an enhanced trench gate structure that results in very low on-state resistance, while also reducing internal capacitance and gate charge for faster and more efficient switching.

Table 1: Device summary

Order code	Marking	Package	Packaging
STL130N6F7	130N6F7	PowerFLAT™ 5x6	Tape and reel

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# 1 Electrical ratings

Table 2: Absolute maximum ratings

Symbol	Parameter	Value	Unit
$V_{DS}$	Drain-source voltage	60	V
$V_{GS}$	Gate-source voltage	$\pm 20$	V
$I_D^{(1)}$	Drain current (continuous) at $T_C = 25\text{ }^\circ\text{C}$	130	A
$I_D^{(1)}$	Drain current (continuous) at $T_C = 100\text{ }^\circ\text{C}$	95	A
$I_{DM}^{(1)(2)}$	Drain current (pulsed)	520	A
$I_D^{(3)}$	Drain current (continuous) at $T_{pcb} = 25\text{ }^\circ\text{C}$	26	A
$I_D^{(3)}$	Drain current (continuous) at $T_{pcb} = 100\text{ }^\circ\text{C}$	19	A
$I_{DM}^{(2)(3)}$	Drain current (pulsed)	104	A
$P_{TOT}^{(1)}$	Total dissipation at $T_C = 25\text{ }^\circ\text{C}$	125	W
$P_{TOT}^{(3)}$	Total dissipation at $T_{pcb} = 25\text{ }^\circ\text{C}$	4.8	W
$T_j$	Operating junction temperature	-55 to 175	$^\circ\text{C}$
$T_{stg}$	Storage temperature		

**Notes:**

- (1) This value is rated according to  $R_{thj-c}$   
 (2) Pulse width limited by safe operating area  
 (3) This value is rated according to  $R_{thj-pcb}$

Table 3: Thermal data

Symbol	Parameter	Value	Unit
$R_{thj-pcb}^{(1)}$	Thermal resistance junction-pcb max.	31.3	$^\circ\text{C/W}$
$R_{thj-case}$	Thermal resistance junction-case max.	1.2	$^\circ\text{C/W}$

**Notes:**

- (1) When mounted on FR-4 board of 1 inch<sup>2</sup>, 2oz Cu,  $t < 10\text{ sec}$

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## 2 Electrical characteristics

( $T_C = 25\text{ }^\circ\text{C}$  unless otherwise specified)

Table 4: On /off states

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{(BR)DSS}$	Drain-source breakdown voltage	$I_D = 1\text{ mA}$ , $V_{GS} = 0\text{ V}$	60			V
$I_{DSS}$	Zero gate voltage drain current	$V_{GS} = 0\text{ V}$ $V_{DS} = 60\text{ V}$			1	$\mu\text{A}$
$I_{GSS}$	Gate-body leakage current	$V_{GS} = 20\text{ V}$ , $V_{DS} = 0\text{ V}$			100	nA
$V_{GS(th)}$	Gate threshold voltage	$V_{DS} = V_{GS}$ , $I_D = 250\text{ }\mu\text{A}$	2		4	V
$R_{DS(on)}$	Static drain-source on-resistance	$V_{GS} = 10\text{ V}$ , $I_D = 13\text{ A}$		0.003	0.0035	$\Omega$

Table 5: Dynamic

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$C_{iss}$	Input capacitance	$V_{DS} = 25\text{ V}$ , $f = 1\text{ MHz}$ , $V_{GS} = 0\text{ V}$	-	2600	-	pF
$C_{oss}$	Output capacitance		-	1200	-	pF
$C_{rss}$	Reverse transfer capacitance		-	115	-	pF
$Q_g$	Total gate charge	$V_{DD} = 30\text{ V}$ , $I_D = 26\text{ A}$ , $V_{GS} = 10\text{ V}$	-	42	-	nC
$Q_{gs}$	Gate-source charge		-	13.6	-	nC
$Q_{gd}$	Gate-drain charge		-	13	-	nC

Table 6: Switching times

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$	Turn-on delay time	$V_{DD} = 30\text{ V}$ , $I_D = 26\text{ A}$ , $R_G = 4.7\text{ }\Omega$ , $V_{GS} = 10\text{ V}$	-	24	-	ns
$t_r$	Rise time		-	44	-	ns
$t_{d(off)}$	Turn-off delay time		-	62	-	ns
$t_f$	Fall time		-	24	-	ns

Table 7: Source-drain diode

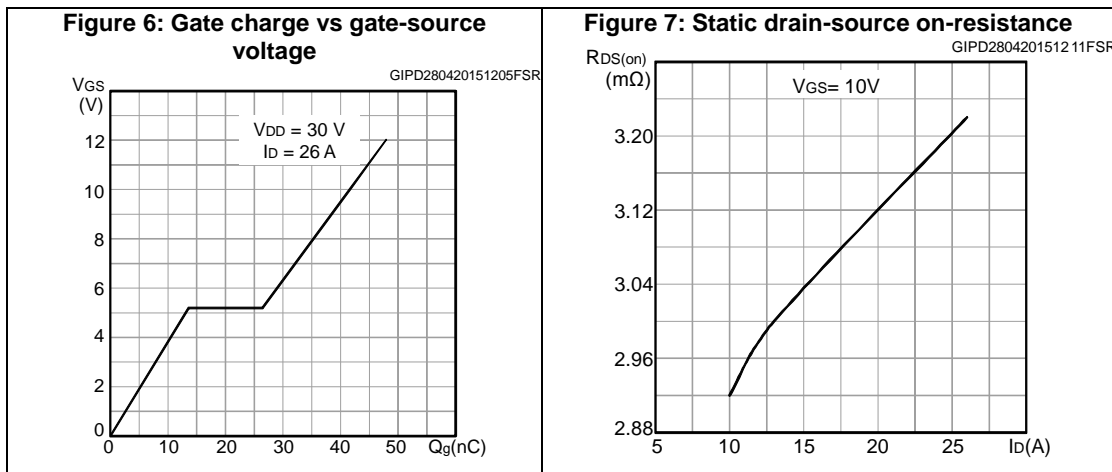
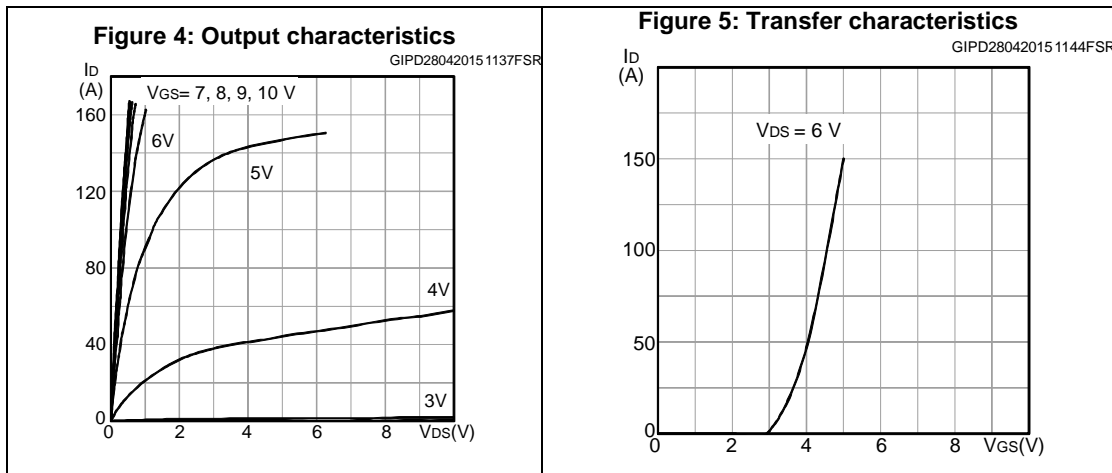
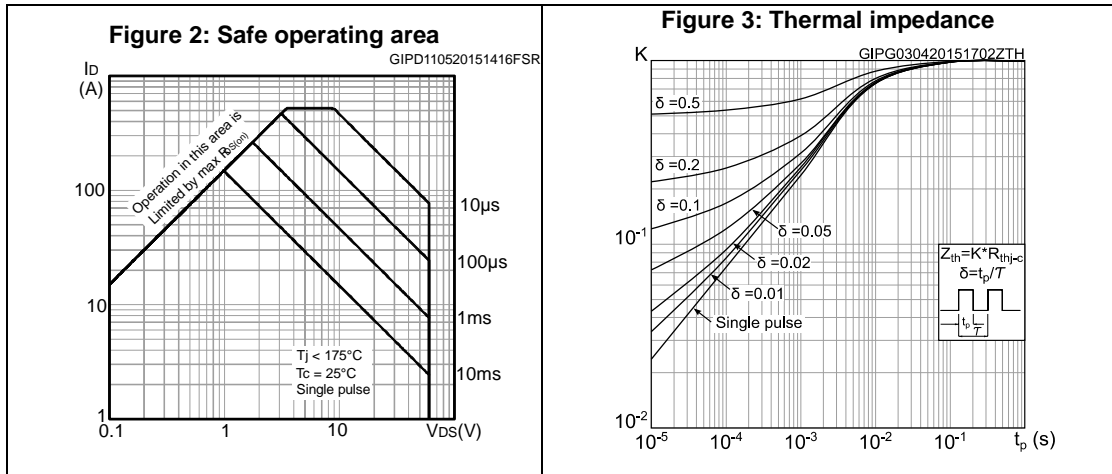
Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{SD}^{(1)}$	Forward on voltage	$I_{SD} = 26\text{ A}$ , $V_{GS} = 0\text{ V}$	-		1.2	V
$t_{rr}$	Reverse recovery time	$I_D = 26\text{ A}$ , $di/dt = 100\text{ A}/\mu\text{s}$ $V_{DD} = 48\text{ V}$	-	50		ns
$Q_{rr}$	Reverse recovery charge		-	56		nC
$I_{RRM}$	Reverse recovery current		-	2.2		A

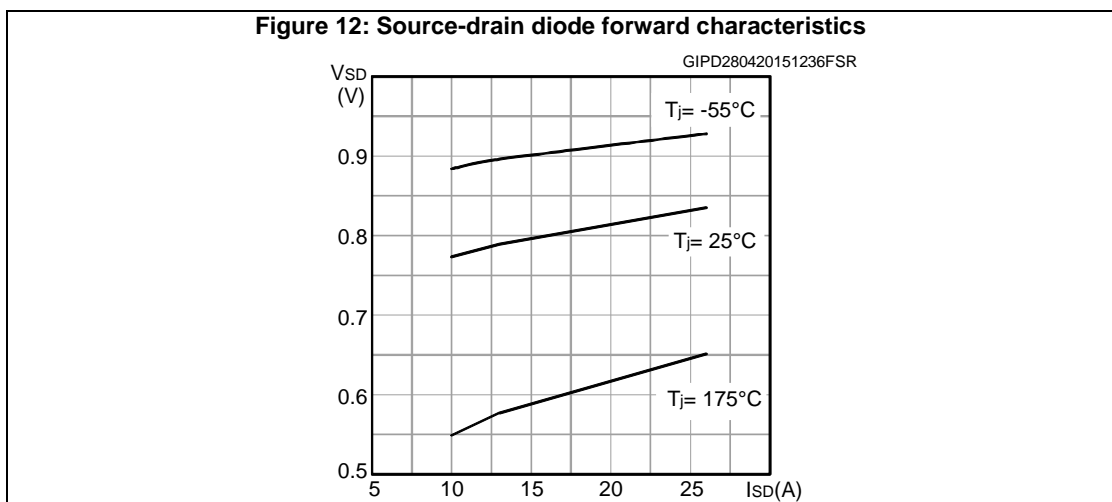
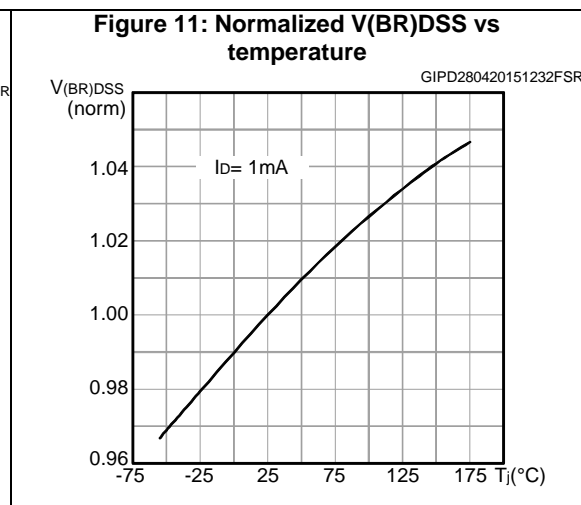
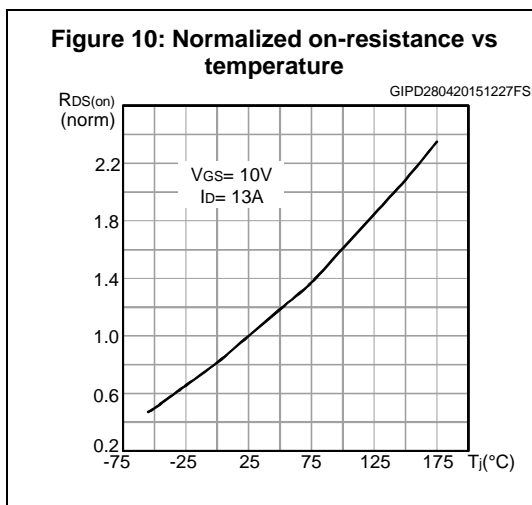
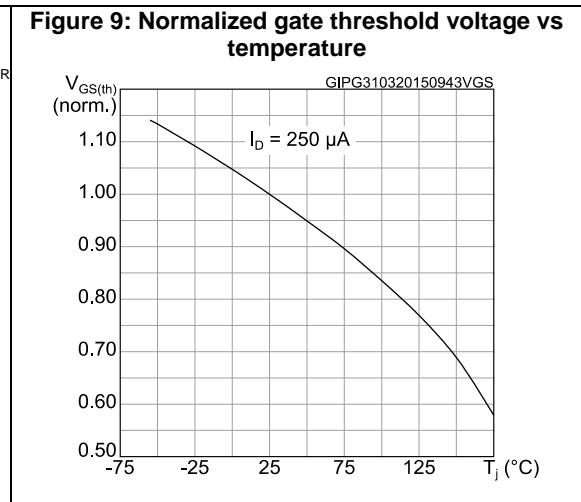
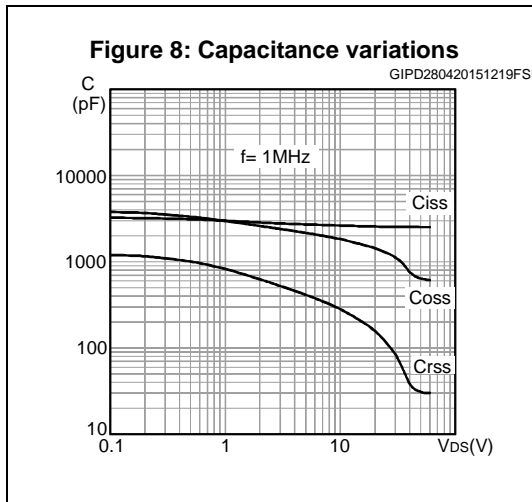
**Notes:**

<sup>(1)</sup>Pulsed: pulse duration = 300  $\mu\text{s}$ , duty cycle 1.5%

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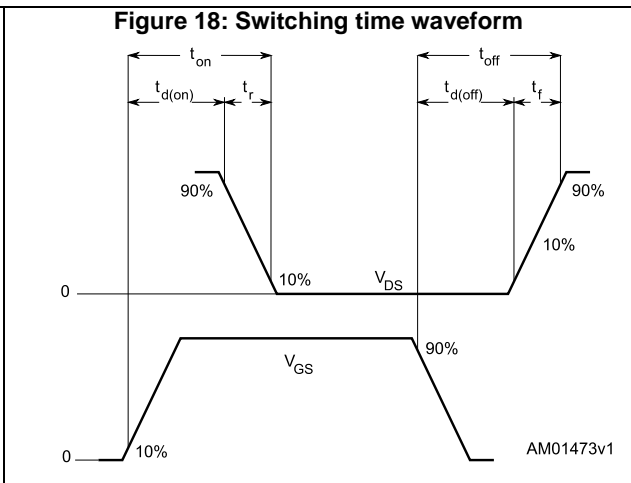
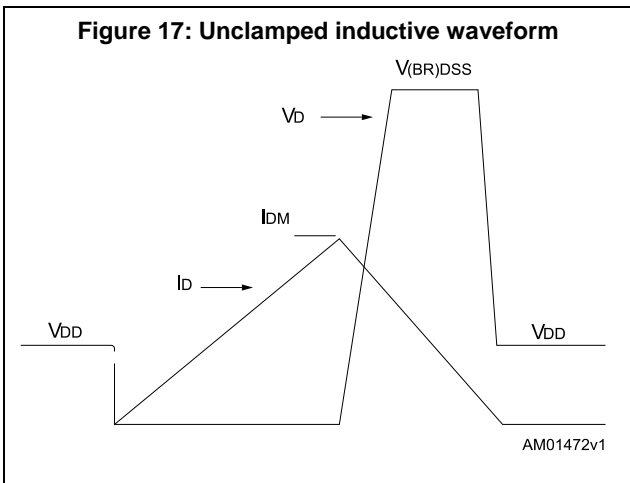
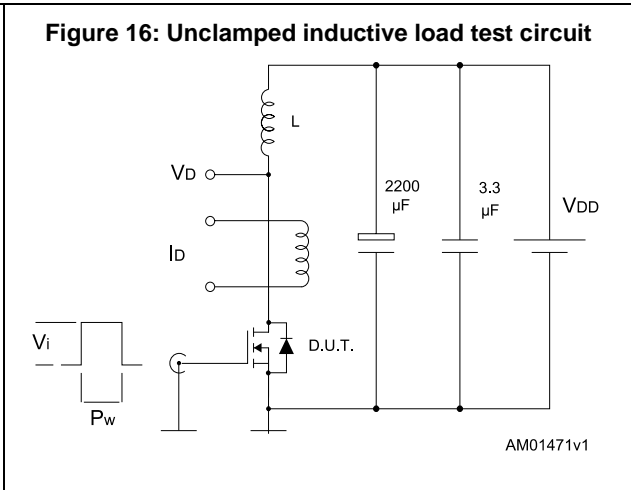
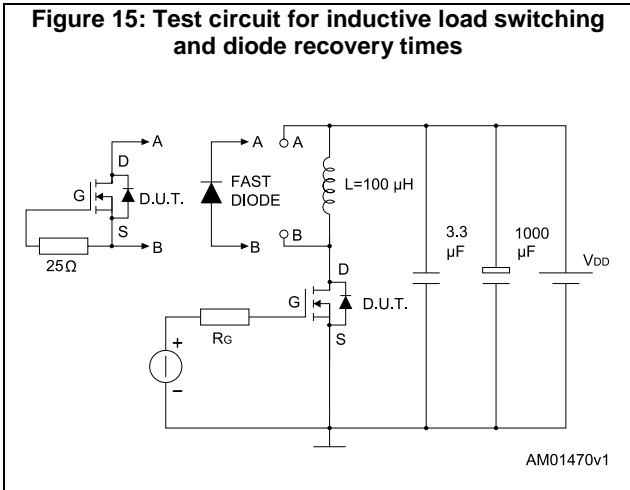
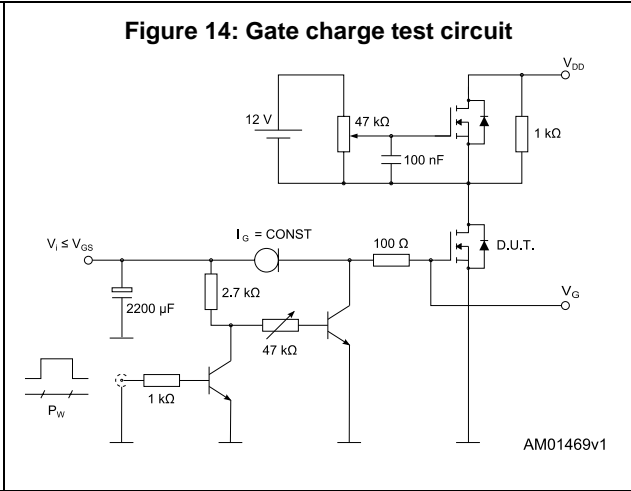
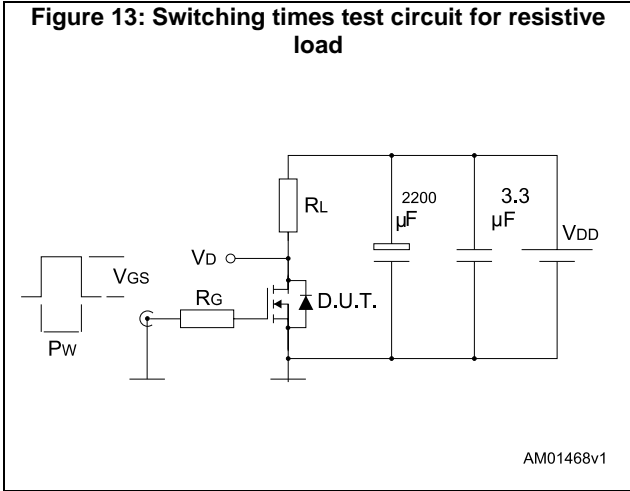
## 2.1 Electrical characteristics (curves)





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### 3 Test circuits



## 4 Package mechanical data

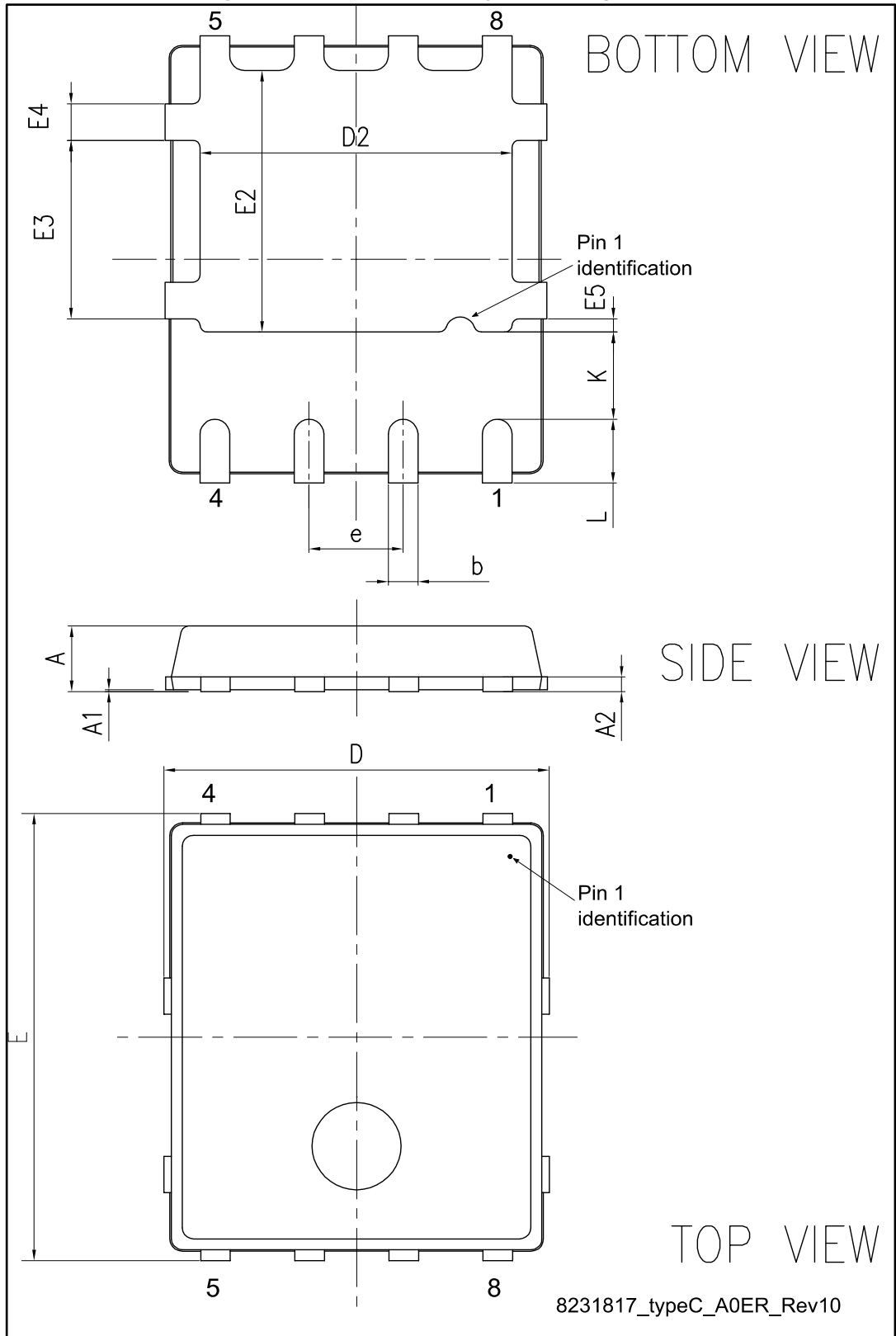
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK<sup>®</sup> is an ST trademark.

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### 4.1 PowerFLAT™ 5x6 type C package information

Figure 19: PowerFLAT™ 5x6 type C package outline

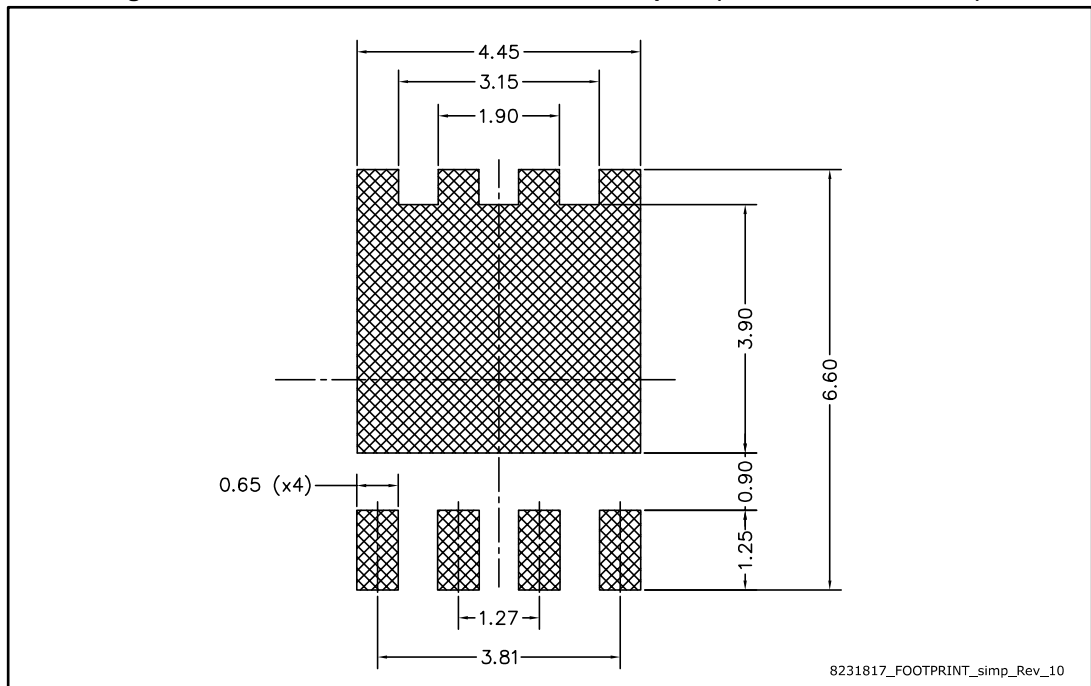


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Table 8: PowerFLAT™ 5x6 type C mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	0.80		1.00
A1	0.02		0.05
A2		0.25	
b	0.30		0.50
D		5.20	
E		6.15	
D2	4.11		4.31
E2	3.50		3.70
e		1.27	
e1		0.65	
L	0.715		1.015
K	1.05		1.35
E3	2.35		2.55
E4	0.40		0.60
E5	0.08		0.28

Figure 20: PowerFLAT™ 5x6 recommended footprint (dimensions are in mm)



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### 4.2 PowerFLAT™ 5x6 packing information

Figure 21: PowerFLAT™ 5x6 tape (dimensions are in mm)

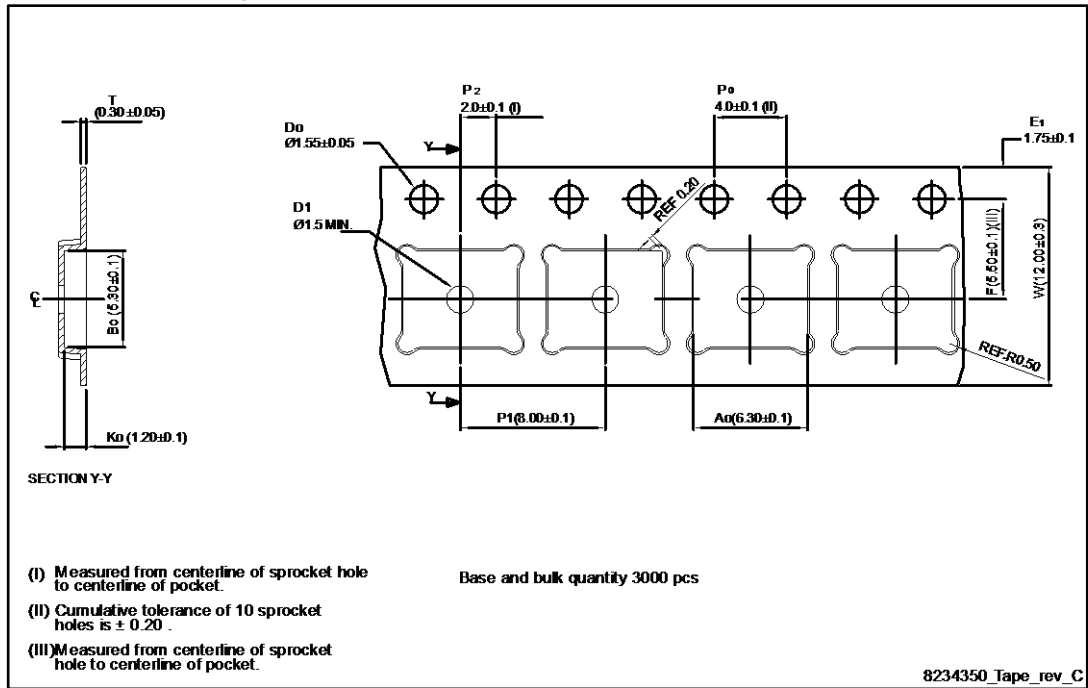
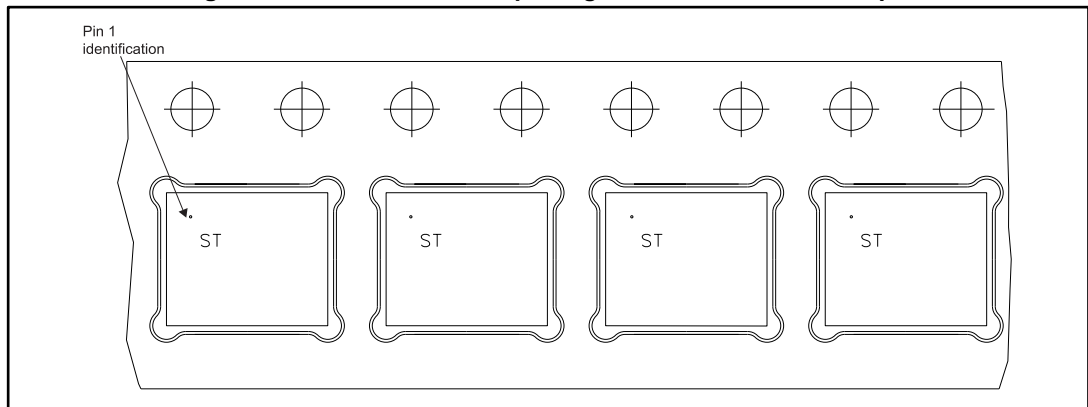
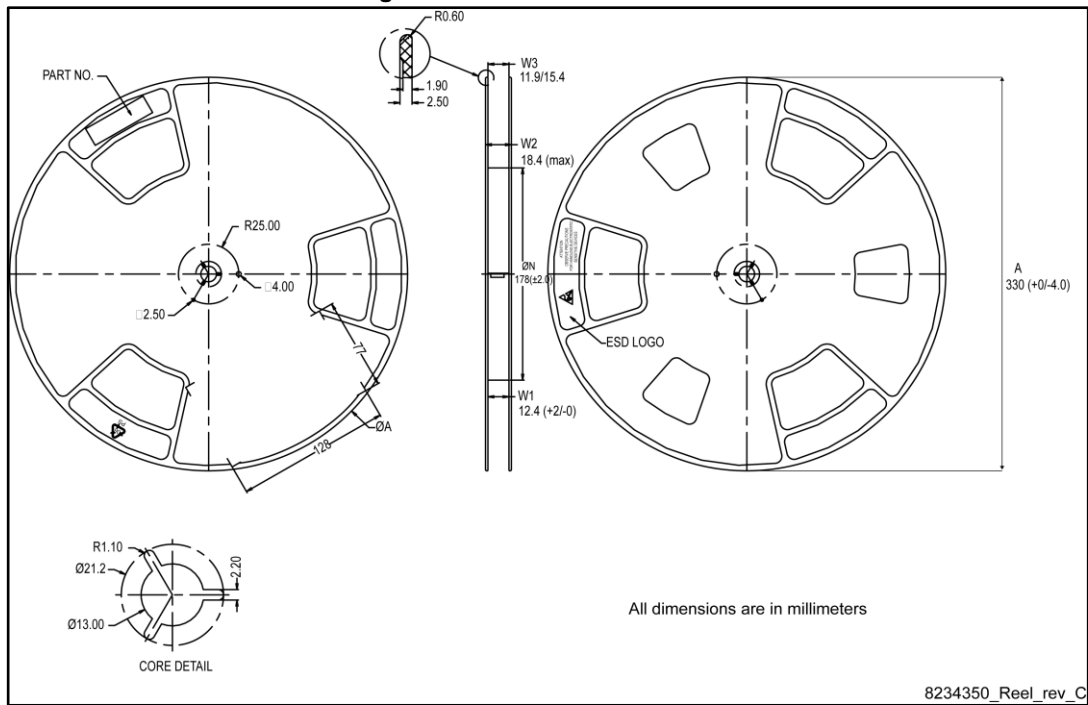


Figure 22: PowerFLAT™ 5x6 package orientation in carrier tape



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Figure 23: PowerFLAT™ 5x6 reel



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## 5 Revision history

**Table 9: Document revision history**

Date	Revision	Changes
17-Feb-2015	1	First release.
11-May-2015	2	Updated and <i>Section 2: "Electrical characteristics"</i> Added <i>Section 2.1: "Electrical characteristics (curves)"</i> Updated <i>Section 4: "Package mechanical data"</i> Minor text changes.
30-Jun-2015	3	Document status promoted from preliminary to production data.

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